

High-Voltage General-Purpose Diode MMBD1401A, MMBD1403A, MMBD1404A, MMBD1405A

Description

Sourced from process 2V.

ABSOLUTE MAXIMUM RATINGS

(T_A = 25°C unless otherwise noted) (Notes 1, 2)

Rating	Symbol	Value	Unit
Working Inverse Voltage	W _{IV}	175	٧
Average Rectified Current	Io	200	mA
DC Forward Current	I _F	600	mA
Recurrent Peak Forward Current	i _f	700	mA
Non-Repetitive Peak Forward Surge Current Pulse Width = 1.0 second Pulse Width = 1.0 microsecond	^j f(surge)	1.0 2.0	A
Storage Temperature Range	T _{STG}	-55 to +150	°C
Operating Junction Temperature	T_J	150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- 1. These ratings are based on a maximum junction temperature of 150°C.
- These are steady-state limits. onsemi should be consulted on applications involving pulsed or low-duty-cycle operations.

THERMAL CHARACTERISTICS

(T_A = 25°C unless otherwise noted) (Note 3)

Characteristic	Symbol	Value	Unit
Power Dissipation	P_{D}	350	mW
Derate Above 25°C		2.8	mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	357	°C/W

^{3.} Device is mounted on glass epoxy PCB 1.6 inch \times 1.6 inch \times 0.06 inch, mounting pad for the collector lead minimum 0.93 in².

ELECTRICAL CHARACTERISTICS

(T_A = 25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Max	Unit
Breakdown Voltage	B _V	I _R = 100 μA	250	_	V
Reverse Current	I _R	V _R = 120 V	-	40	nA
		V _R = 175 V	-	100	nA
Forward Voltage	V _F	I _F = 10 mA	-	800	mV
		I _F = 50 mA	760	920	mV
		I _F = 200 mA	-	1.1	V
		I _F = 300 mA	-	1.25	V
Diode Capacitance	Co	V _R = 0, f = 1.0 MHz	-	2.0	pF
Reverse Recovery Time	t _{rr}	$I_F = I_R = 30 \text{ mA},$ $I_{RR} = 3.0 \text{ mA},$ $R_L = 100 \Omega$	-	50	ns

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

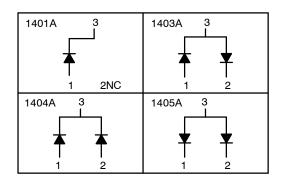


SOT-23 CASE 318BM



SOT-23 CASE 318-08

CONNECTION DIAGRAMS



MARKING DIAGRAM



AXX = Specific Device CodeXX = 29/32/33/34

M = Date Code

■ = Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping [†]
MMBD1401A	SOT-23 (Pb-Free)	3000 / Tape & Reel
MMBD1403A	SOT-23 (Pb-Free)	3000 / Tape & Reel
MMBD1404A	SOT-23 (Pb-Free)	3000 / Tape & Reel
MMBD1405A	SOT-23 (Pb-Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MMBD1401A, MMBD1403A, MMBD1404A, MMBD1405A

TYPICAL CHARACTERISTICS

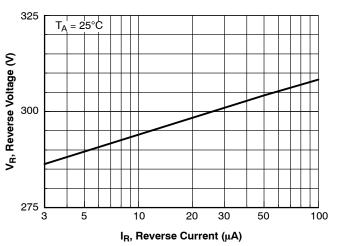


Figure 1. Reverse Voltage vs. Reverse Current $B_V = 1.0$ to $100~\mu A$

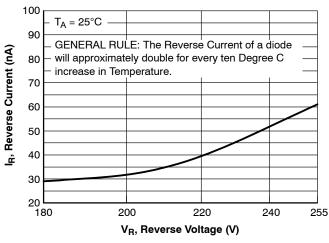


Figure 3. Reverse Current vs. Reverse Voltage I_R – 180 to 255 V

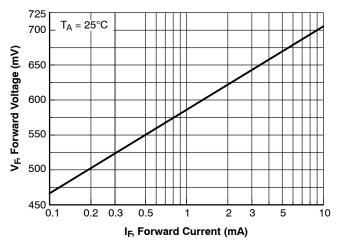


Figure 5. Forward Voltage vs. Forward Current V_F – 0.1 to 10 mA

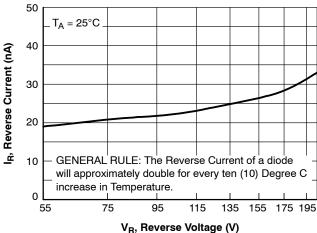


Figure 2. Reverse Current vs. Reverse Voltage I_R – 55 to 205 V

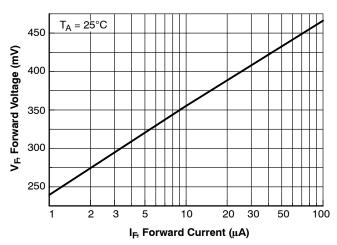


Figure 4. Forward Voltage vs. Forward Current $V_F - 1.0$ to $100 \mu A$

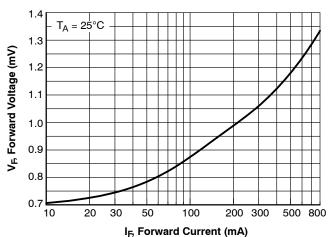


Figure 6. Forward Voltage vs. Forward Current $V_F - 10$ to 800 mA

MMBD1401A, MMBD1403A, MMBD1404A, MMBD1405A

TYPICAL CHARACTERISTICS (Continued)

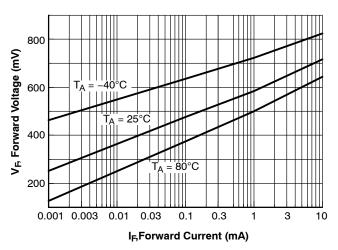


Figure 7. Forward Voltage vs. Ambient Temperature, V_F – 1.0 μA – 10 mA (–40 to +80°C)

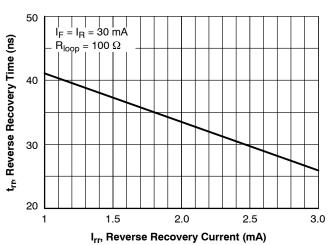


Figure 9. Reverse Recovery Time vs. Reverse Recovery Current (I_{rr})

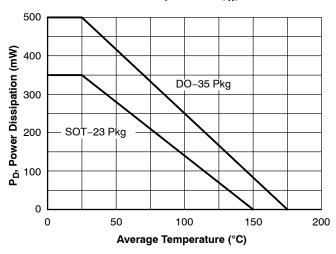


Figure 11. Power Derating Curve

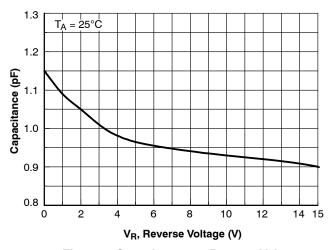


Figure 8. Capacitance vs. Reverse Voltage

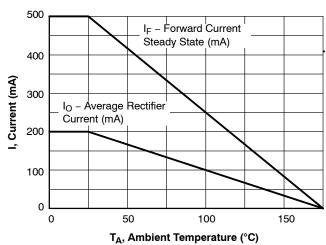


Figure 10. Average Rectified Current (I_O) and Forward Current (I_F) vs. Ambient Temperature (T_A)

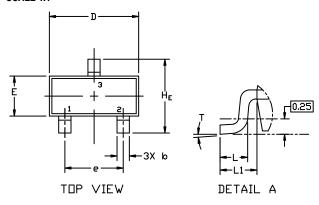


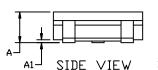


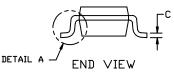
SOT-23 (TO-236) **CASE 318 ISSUE AT**

DATE 01 MAR 2023









NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M,1994.
- CONTROLLING DIMENSION: MILLIMETERS
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL.
- DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

	MILLIM	ETERS		INCHES		
DIM	MIN.	N□M.	MAX.	MIN.	N□M.	MAX.
Α	0.89	1.00	1.11	0.035	0.039	0.044
A1	0.01	0.06	0.10	0.000	0.002	0.004
b	0.37	0.44	0.50	0.015	0.017	0.020
С	0.08	0.14	0.20	0.003	0.006	0.008
D	2.80	2.90	3.04	0.110	0.114	0.120
Ε	1.20	1.30	1.40	0.047	0.051	0.055
e	1.78	1.90	2.04	0.070	0.075	0.080
L	0.30	0.43	0.55	0.012	0.017	0.022
L1	0.35	0.54	0.69	0.014	0.021	0.027
HE	2.10	2.40	2.64	0.083	0.094	0.104
Т	0*		10°	0*		10°

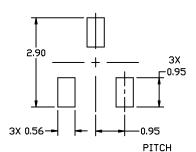
GENERIC MARKING DIAGRAM*



XXX = Specific Device Code

= Date Code

= Pb-Free Package



RECOMMENDED MOUNTING FOOTPRINT

For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.

STYLES ON PAGE 2

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DESCRIPTION:	SOT-23 (TO-236)		PAGE 1 OF 2	

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^{*}This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "=", may or may not be present. Some products may not follow the Generic Marking.

MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS



SOT-23 (TO-236) CASE 318 ISSUE AT

DATE 01 MAR 2023

STYLE 1 THRU 5: CANCELLED	STYLE 6: PIN 1. BASE 2. EMITTER 3. COLLECTOR	STYLE 7: PIN 1. EMITTER 2. BASE 3. COLLECTOR	STYLE 8: PIN 1. ANODE 2. NO CONNECTION 3. CATHODE	N	
STYLE 9:	STYLE 10:	STYLE 11:	STYLE 12: PIN 1. CATHODE 2. CATHODE 3. ANODE	STYLE 13:	STYLE 14:
PIN 1. ANODE	PIN 1. DRAIN	PIN 1. ANODE		PIN 1. SOURCE	PIN 1. CATHODE
2. ANODE	2. SOURCE	2. CATHODE		2. DRAIN	2. GATE
3. CATHODE	3. GATE	3. CATHODE-ANODE		3. GATE	3. ANODE
STYLE 15:	STYLE 16:	STYLE 17:	STYLE 18:	STYLE 19:	STYLE 20:
PIN 1. GATE	PIN 1. ANODE	PIN 1. NO CONNECTION	PIN 1. NO CONNECTION	N PIN 1. CATHODE	PIN 1. CATHODE
2. CATHODE	2. CATHODE	2. ANODE	2. CATHODE	2. ANODE	2. ANODE
3. ANODE	3. CATHODE	3. CATHODE	3. ANODE	3. CATHODE-ANODE	3. GATE
STYLE 21:	STYLE 22:	STYLE 23:	STYLE 24:	STYLE 25:	STYLE 26:
PIN 1. GATE	PIN 1. RETURN	PIN 1. ANODE	PIN 1. GATE	PIN 1. ANODE	PIN 1. CATHODE
2. SOURCE	2. OUTPUT	2. ANODE	2. DRAIN	2. CATHODE	2. ANODE
3. DRAIN	3. INPUT	3. CATHODE	3. SOURCE	3. GATE	3. NO CONNECTION
STYLE 27: PIN 1. CATHODE 2. CATHODE 3. CATHODE	STYLE 28: PIN 1. ANODE 2. ANODE 3. ANODE				

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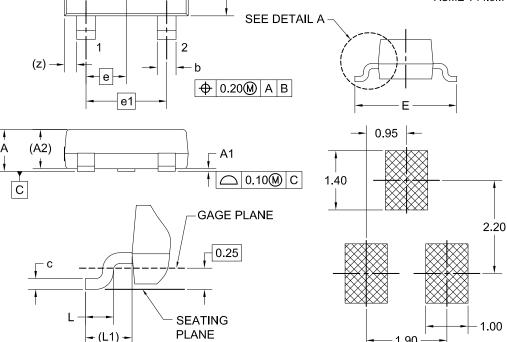


SOT-23 CASE 318BM **ISSUE A**

DATE 01 SEP 2021

NOTES: UNLESS OTHERWISE SPECIFIED

- A) REFERENCE JEDEC REGISTRATION TO-236, VARIATION AB, ISSUE H.
- B) ALL DIMENSIONS ARE IN MILLIMETERS.
- C) DIMENSIONS ARE INCLUSIVE OF BURRS, MOLD FLASH AND TIE BAR EXTRUSIONS.
- D) DIMENSIONING AND TOLERANCING PER ASME Y14.5M - 2009.



Α

В

E1

2000.				
DIM	MILLIMETERS			
	MIN.	NOM.	MAX.	
Α			1.20	
A1	0.00	0.05	0.10	
A2	0.93 REF			
b	0.37	0.44	0.60	
С	0.08	0.15	0.23	
D	2.72	2.92	3.12	
Е	2.10	2.40	2.70	
E1	1.15	1.30	1.50	
е	(0.95 BSC	;	
e1	1.90 BSC			
L	0.20			
L1	0.55 REF			
z	0.29 REF			



DETAIL A



*FOR ADDITIONAL INFORMATION ON OUR PB-FREE STRATEGY AND SOLDERING DETAILS, PLEASE DOWNLOAD THE ON SEMICONDUCTOR SOLDERING AND MOUNTING TECHNIQUES REFERENCE MANUAL, SOLDERRM/D.

1.90

LAND PATTERN RECOMMENDATION

XXX = Specific Device Code = Date Code

= Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

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